SHI LING® 浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

‟ ن Ӟ

Specifcation of products

‟ ن ﭒ : 刀

‟ ن گ：MFDK200U7NK3

ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

Ж Ɦ Ы

Ж Є 0578 S 3615066

Ж 323000

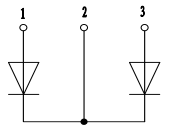
E-mail:smrshiling12@163.com

Http//www.smrshiling.com

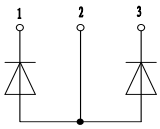
刂		8
	’ ₩	▫

گ Ж 02 Ж 2026.5





MFDK200U7NK3



MFDA200U7NK3

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise speci /dtI

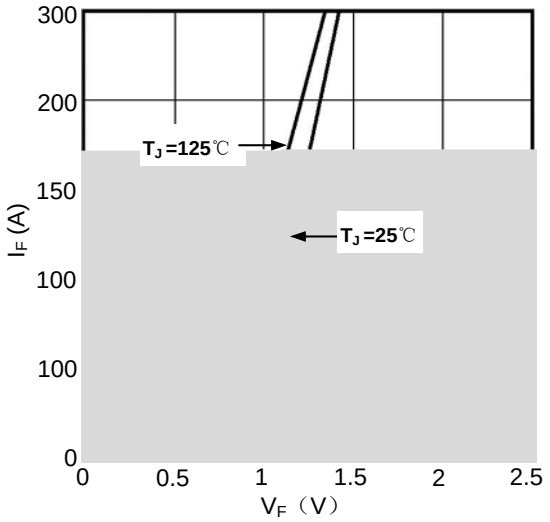


Figure1. Forward Voltage Drop vs Forward Current

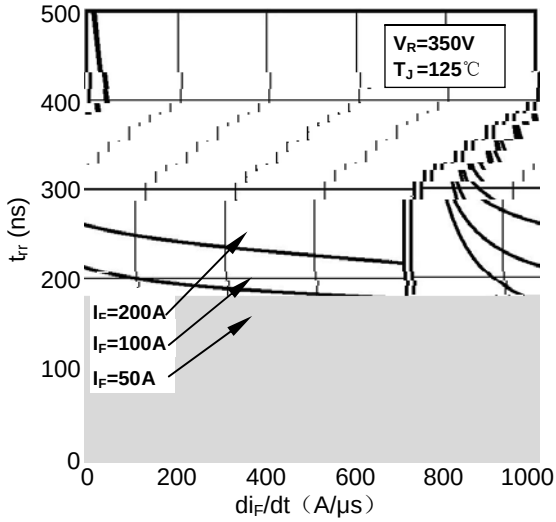


Figure2. Reverse Recovery Time vs di_F/dt

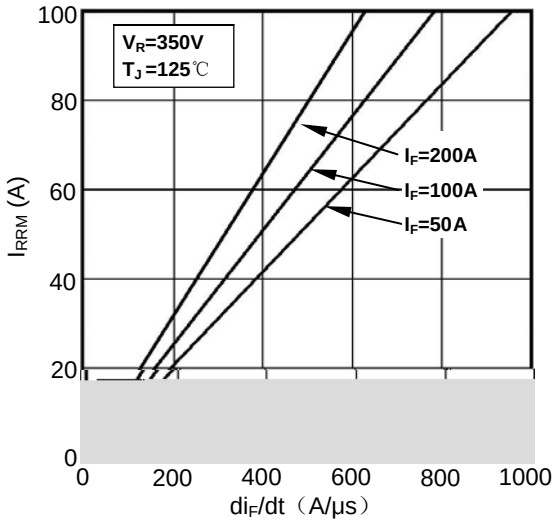


Figure3. Reverse Recovery Current vs di_F/dt

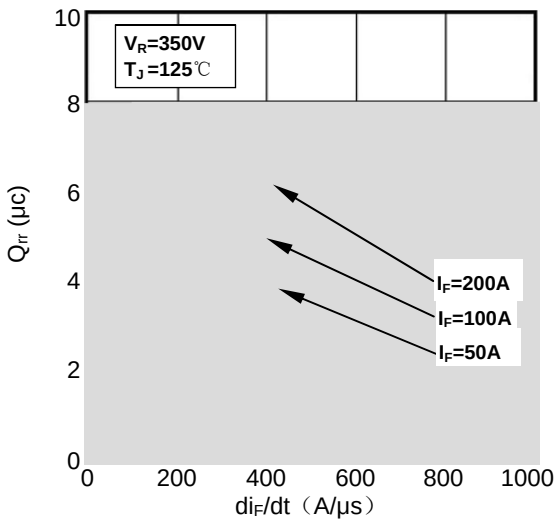


Figure4. Reverse Recovery Charge vs di_F/dt

IIIII

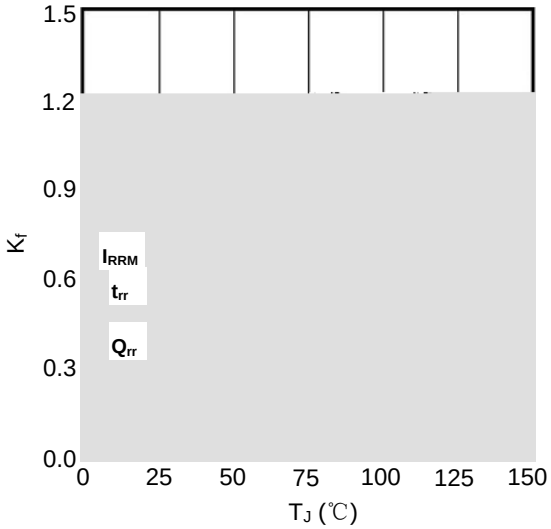


Figure5. Dynamic Parameters vs Junction Temperature

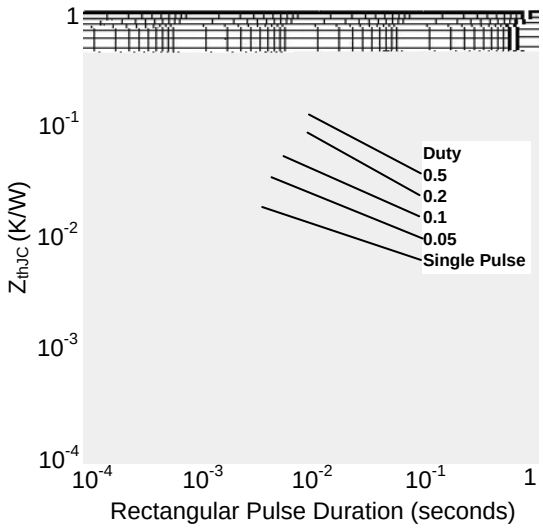
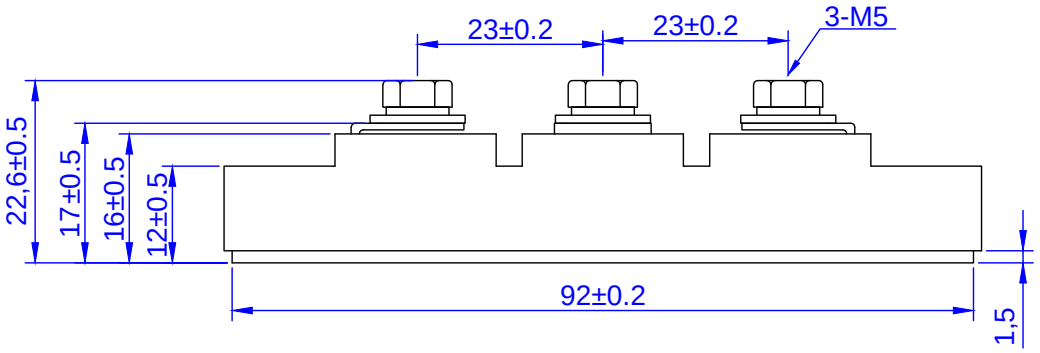
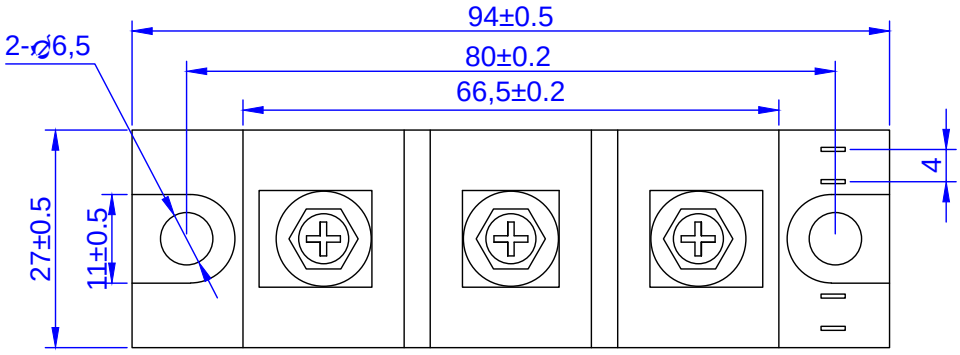


Figure6. Transient Thermal Impedance

Packa ❦ Outlin❦s





Unit:mm